NSN 5961-00-137-1000

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Semiconductor Device Set - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-137-1000 **Inclosure Material:** Plastic all transistor **Overall Length:** 0.170 inches and 0.210 inches all transistor **Terminal Length:** 0.500 inches all transistor **Overall Height:** 0.125 inches and 0.165 inches all transistor **Overall Width:** 0.175 inches and 0.205 inches all transistor **Internal Configuration:** Field effect all transistor **Channel Polarity And Control Type (non-core):** N-channel insulated gate type all transistor Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-92 all transistor **Component Function Relationship:** Matched **Component Name And Quantity:** 2 transistor **Mounting Method:** Terminal all transistor **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 15.0 drain to source voltage all transistor **Current Rating Per Characteristic:** 2.00 milliamperes zero-gate-voltage drain current and 20.00 milliamperes zero-gate-voltage source current megawatts all transistor **Power Rating Per Characteristic:** 300.0 milliwatts small-signal input power, common-collector absolute all transistor **Terminal Type And Quantity:** 2 uninsulated wire lead all transistor Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: